

HIGH-SPEED (200 kbps) ANALOG OUTPUT TYPE
5-PIN SOP PHOTOCOUPLER

-NEPOC Series-

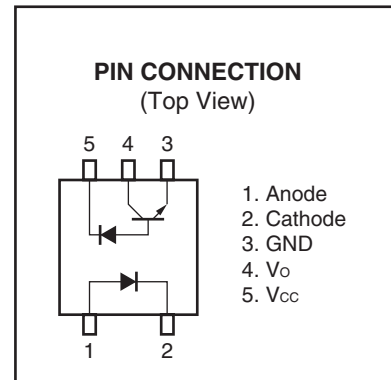
DESCRIPTION

The PS8103 is an optically coupled isolator containing a GaAs LED on the light emitting diode (input side) and a PIN photodiode and a high-speed amplifier transistor on the output side on one chip.

This is a plastic SOP (Small Out-line Package) type for high density applications.

FEATURES

- Wide operating V_{CC} range ($V_{CC} = -0.5$ to $+15$ V)
- Small package (5-pin SOP)
- High isolation voltage ($BV = 2\ 500$ Vr.m.s.)
- High-speed response ($t_{PHL}, t_{PLH} = 5\ \mu s$ MAX. (@ $R_L = 4.1\ k\Omega$)
- Ordering number of taping product: PS8103-F3, F4: 2 500 pcs/reel
- Pb-Free product
- Safety standards
 - UL approved: File No. E72422

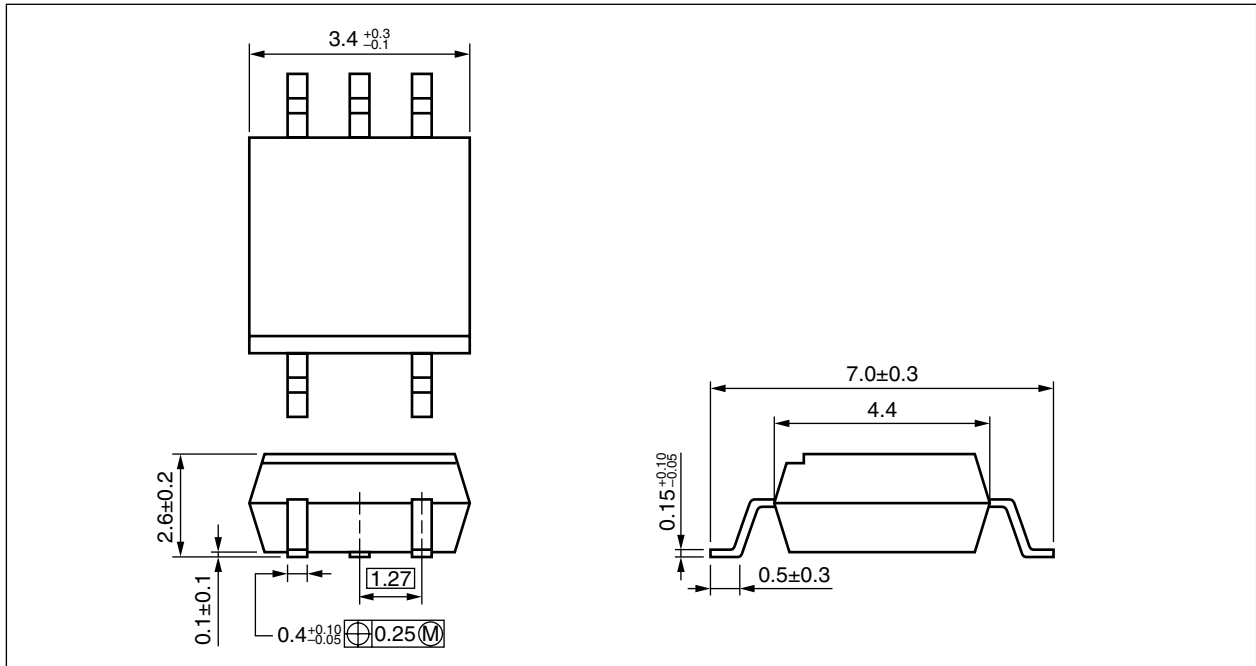


APPLICATIONS

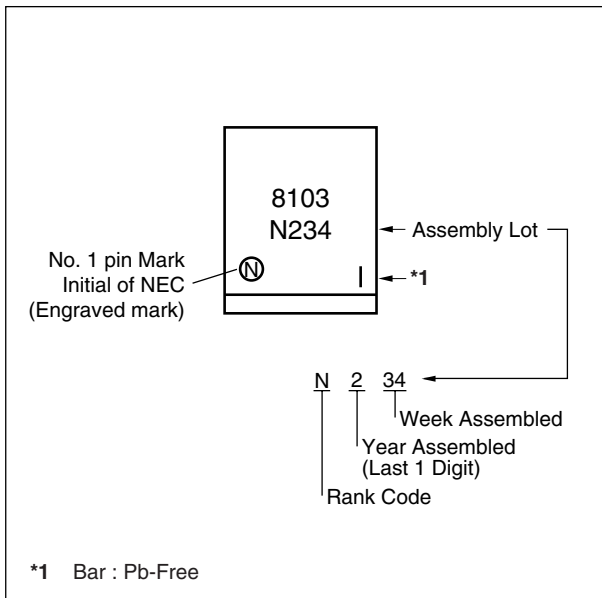
- Computer and peripheral manufactures
- General purpose inverter
- Substitutions for relays and pulse transformers
- Power supply

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PACKAGE DIMENSIONS (UNIT: mm)



MARKING EXAMPLE



★ ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{*1}
PS8103	PS8103-A	Pb-Free	20 pcs (Tape 20 pcs cut)	Standard products (UL approved)	PS8103
PS8103-F3	PS8103-F3-A		Embossed Tape 2 500 pcs/reel		
PS8103-F4	PS8103-F4-A				

*1 For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current	I _F	50	mA
	Reverse Voltage	V _R	5	V
	Power Dissipation ^{*1}	P _D	50	mW
Detector	Supply Voltage	V _{CC}	-0.5 to +15	V
	Output Voltage	V _O	-0.5 to +15	V
	Output Current	I _O	8	mA
	Power Dissipation ^{*2}	P _C	80	mW
Isolation Voltage ^{*3}		BV	2 500	Vr.m.s.
Operating Ambient Temperature		T _A	-40 to +100	°C
Storage Temperature		T _{stg}	-55 to +125	°C

*1 Reduced to 0.5 mW/°C at T_A = 25°C or more.

*2 Applies to output pin V_O. Reduced to 0.8 mW/°C at T_A = 25°C or more.

*3 AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output.

★ Pins 1-2 shorted together, 3-5 shorted together.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

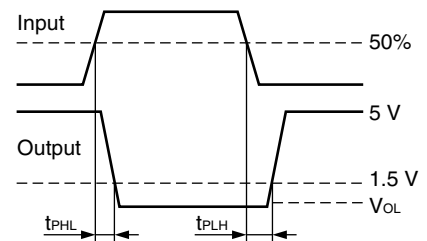
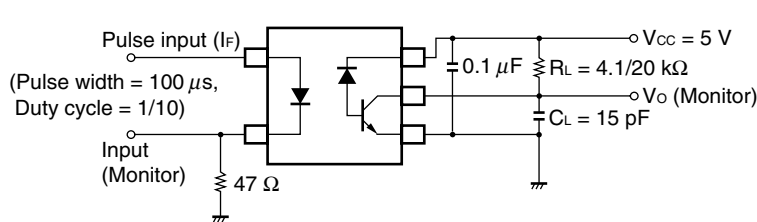
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = 16 mA		1.2	1.5	V
	Reverse Current	I _R	V _R = 3 V			10	μA
	Terminal Capacitance	C _t	V = 0 V, f = 1 MHz		30		pF
Detector	High Level Output Current	I _{OH} (1)	I _F = 0 mA, V _{CC} = V _O = 5.5 V		7	500	nA
	High Level Output Current	I _{OH} (2)	I _F = 0 mA, V _{CC} = V _O = 15 V			100	μA
	Low Level Output Voltage	V _{OL}	I _F = 16 mA, V _{CC} = 4.5 V, I _{OL} = 1.1 mA		0.1	0.4	V
	High Level Supply Current	I _{CCH}	I _F = 0 mA, V _O = open, V _{CC} = 15 V		0.01	1	μA
	Low Level Supply Current	I _{CCL}	I _F = 16 mA, V _O = open, V _{CC} = 15 V		150	800	
Coupled	Current Transfer Ratio (I _C /I _F) ⁻¹	CTR	I _F = 16 mA, V _{CC} = 4.5 V, V _O = 0.4 V	10	23	30	%
	Isolation Resistance	R _{I-O}	V _{I-O} = 1 kV _{DC} , R _H = 40 to 60%	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Propagation Delay Time (H → L) ²	t _{PHL}	I _F = 16 mA, V _{CC} = 5 V, R _L = 4.1 kΩ, C _L = 15 pF		1	5	μs
	Propagation Delay Time (L → H) ²	t _{PLH}			2	5	
	Propagation Delay Time (H → L) ²	t _{PHL}	I _F = 16 mA, V _{CC} = 5 V, R _L = 20 kΩ, C _L = 15 pF		1	15	
	Propagation Delay Time (L → H) ²	t _{PLH}			7	15	

***1 CTR rank**

L : 15 to 30 (%)

N : 10 to 30 (%)

***2 Test circuit for propagation delay time**



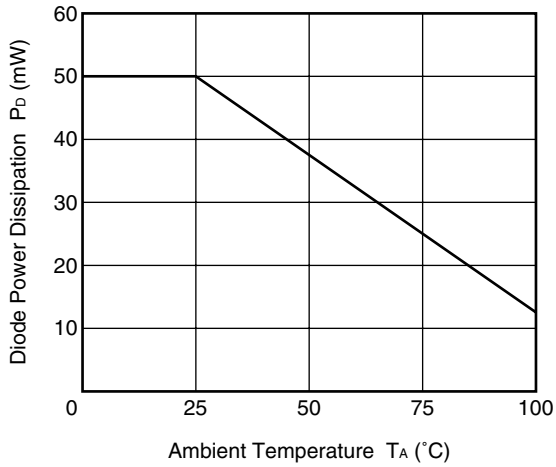
C_L includes probe and stray wiring capacitance.

USAGE CAUTIONS

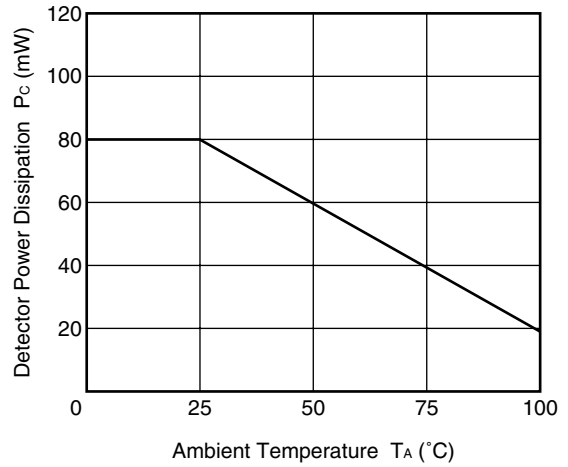
1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of 0.1 μF is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
3. Avoid storage at a high temperature and high humidity.

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

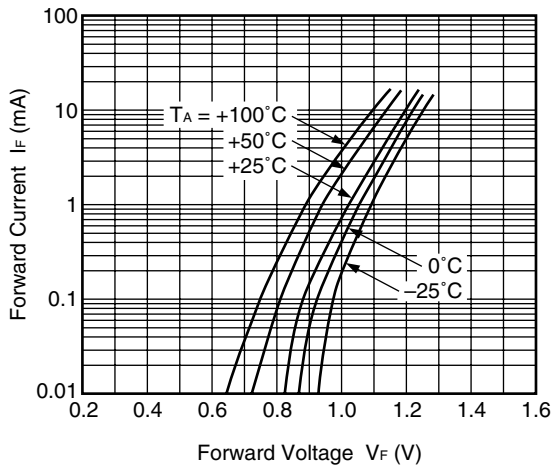
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



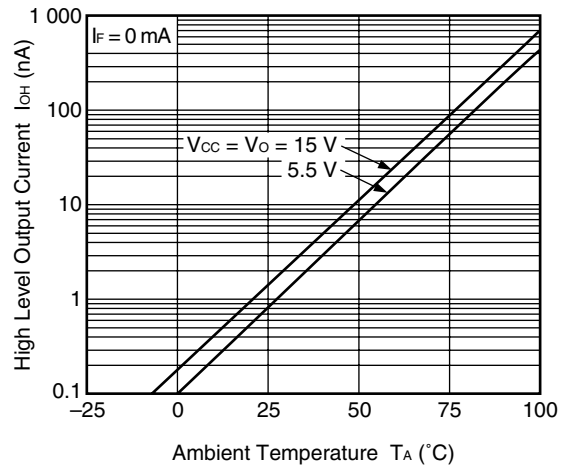
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



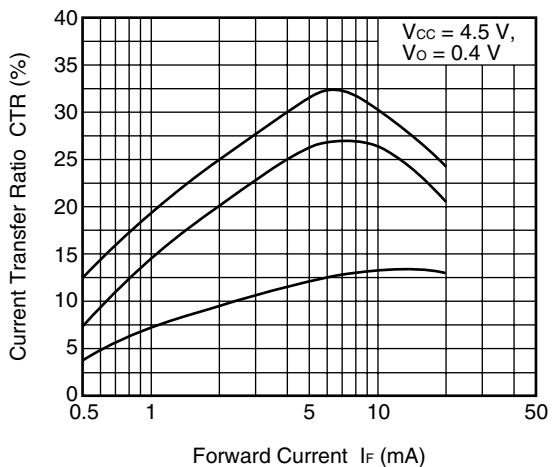
FORWARD CURRENT vs. FORWARD VOLTAGE



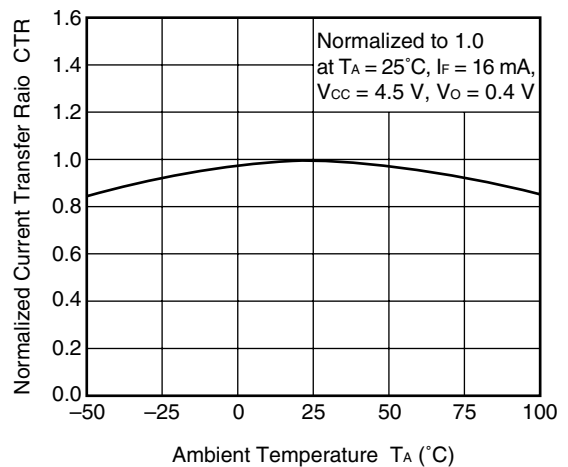
HIGH LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE



CURRENT TRANSFER RATIO vs. FORWARD CURRENT

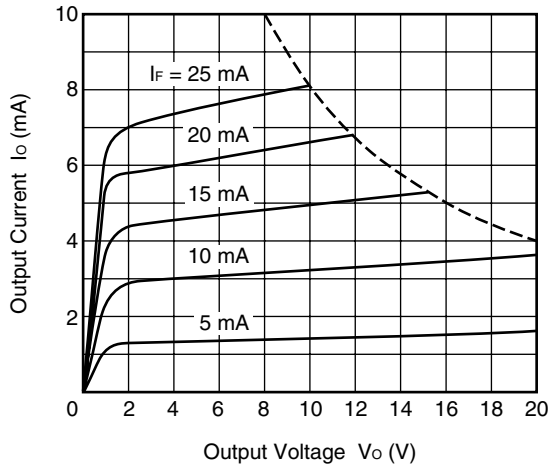


NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE

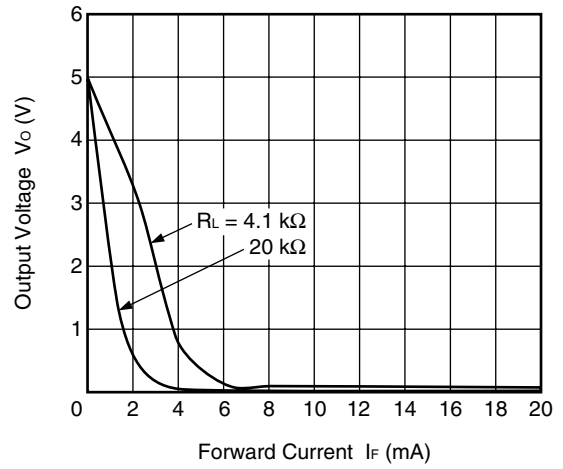


Remark The graphs indicate nominal characteristics.

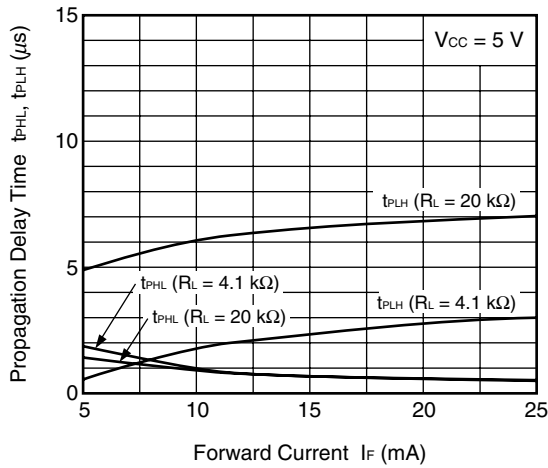
OUTPUT CURRENT vs. OUTPUT VOLTAGE



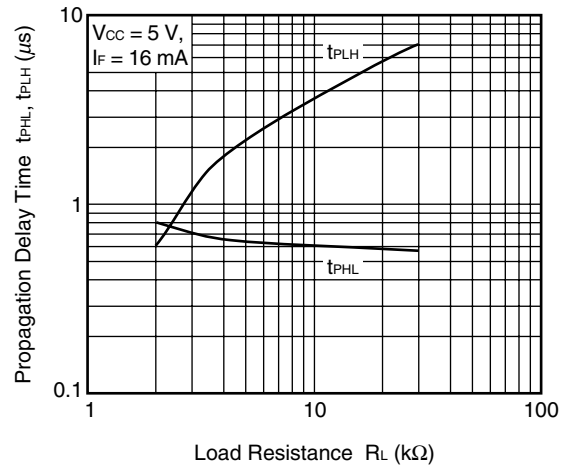
OUTPUT VOLTAGE vs. FORWARD CURRENT



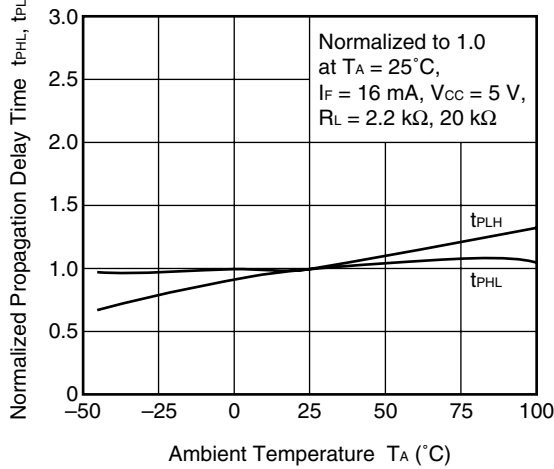
PROPAGATION DELAY TIME vs. FORWARD CURRENT



PROPAGATION DELAY TIME vs. LOAD RESISTANCE



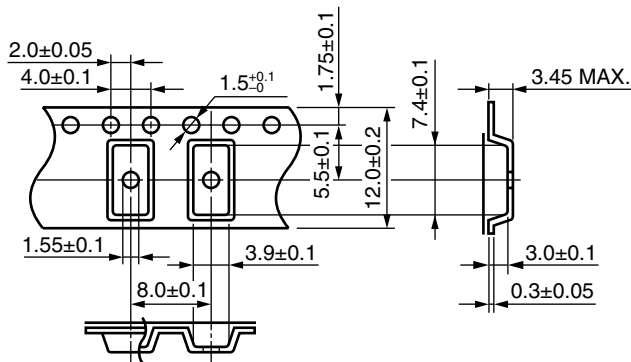
NORMALIZED PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



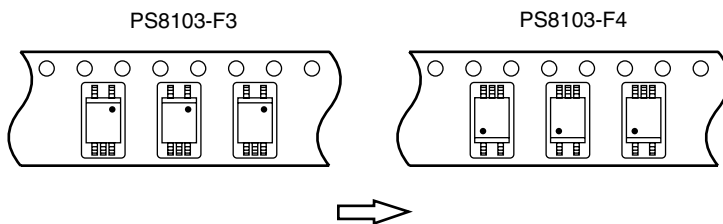
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

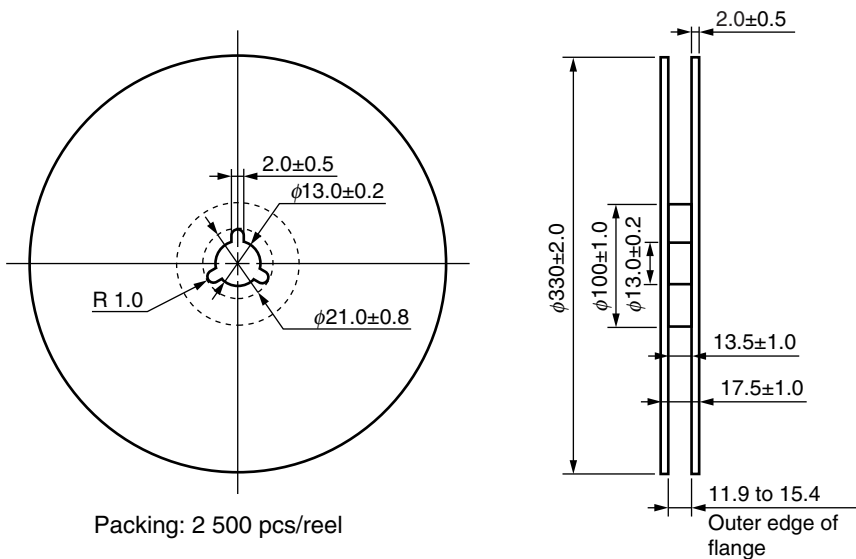
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



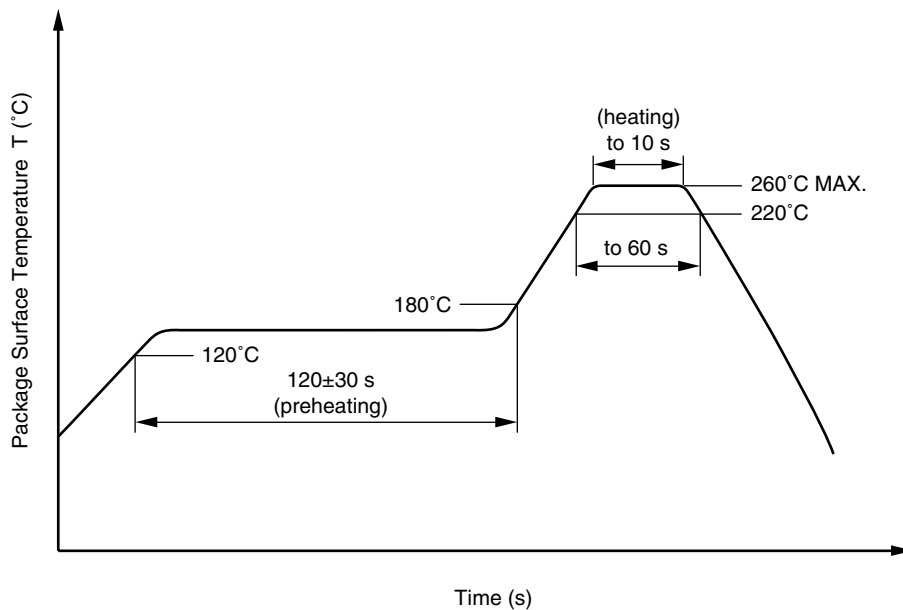
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350°C or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

- Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

USAGE CAUTIONS

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

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- M8E 00.4-0110

<p>Caution</p>	<p>GaAs Products</p>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. <ol style="list-style-type: none"> 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.
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► For further information, please contact

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